

Lnr: D395 Tec: FBG

| Total Results Mean:     | Failure Rate<br>fit | MTBF<br>h | MTBF<br>a |
|-------------------------|---------------------|-----------|-----------|
| EN/IEC 61709 (SN 29500) | 5 411               | 184 801   | 21,1      |

Missing component or operating data leads to the following result range:

EN/IEC 61709 (SN 29500): Failure Rate: 5 373 - 5 450 fit MTBF: 20,9 - 21,2 a

The results are valid under following conditions:

- SNA: Nonmobile operation ground benign
- Tu: 40°C mean component ambient temperature
- Zf: Continuous operation 8760 h per year

Individual application data considered for 0 out of 225 positions

1 fit equals one failure per 10<sup>9</sup> component hours

Mean failure rates of the component groups: EN/IEC 61709 (SN 29500)

| Quantity | Component Group                   | fit   | Percent. |
|----------|-----------------------------------|-------|----------|
| 50       | Transistors                       | 1 518 | 28,1 %   |
| 579      | Capacitors                        | 1 225 | 22,6 %   |
| 42       | Connectors Sockets                | 972   | 18 %     |
| 5        | Micro-Processors and -Controllers | 550   | 10,2 %   |
| 44       | Other Components                  | 253   | 4,7 %    |
| 17       | IC analogue                       | 247   | 4,6 %    |
|          | Electr. Connections               | 225   | 4,2 %    |
| 487      | Resistors                         | 107   | 2 %      |
| 12       | IC Standard                       | 101   | 1,9 %    |
| 5        | IC ASIC and A/D D/A Converters    | 75    | 1,4 %    |
| 1        | IC Memories                       | 70    | 1,3 %    |
| 28       | Diodes                            | 49    | 0,9 %    |
| 7        | Optoelectronics                   | 19    | 0,4 %    |
| 1 277    | Sum                               | 5 411 | 100 %    |

Failure rates for all positions of the Quality-list:

Items with individual stress data considered are marked by +  
 Items using individual base failure rates are marked by «

| Quantity | Description   | Type    | Failure Rate single | FR total |
|----------|---|---------|---------------------|----------|
| 174      | V26803-B102-V44,Bac=4130,Tec=2000,Gec=SMT,Capacitor ceramic MDC,Umax=16,Zfr=100%,Tref=40,Ar=2,Vuv=.5,C x7r                                      | SN 2    |                     | 348 fit  |
| 2        | V26801-B100-V519,Bac=4230,Geh=SMT/2,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2  |                     | 0,4 fit  |
| 34       | V26801-B100-V200,Bac=4230,Gec=SMT,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2  |                     | 6,8 fit  |
| 1        | V26827-B442-V115,Bac=5211,Tec=2000,Conn./socket ins. without el. load gold multiple cont. 1155 pins,Vf=1155,Zfr=100%,Tref=40 Ar=0.05,BGA Socket | SN 57.8 |                     | 57,8 fit |
| 59       | V26803-B93-V4,Bac=4130,Tec=2000,Gec=SMT,Capacitor ceramic MDC,Tbmax=85,Umax=16,Zfr=100%,Tref=40,Ar=2,Vuv=.5,Ceramic Capacitor                   | SN 2    |                     | 118 fit  |
| 39       | V26803-B102-V9,Bac=4130,Tec=2000,Gec=SMT,Capacitor ceramic MDC,Umax=50,Zfr=100%,Tref=40,Ar=2,Vuv=.5,C x7r                                       | SN 2    |                     | 78 fit   |
| 11       | V26801-B100-V501,Bac=4230,Gec=SMT,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2  |                     | 2,2 fit  |
| 12       | V26801-B100-V644,Bac=4230,Geh=SMT/2,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2  |                     | 2,4 fit  |
| 2        | V26801-B100-V550,Bac=4230,Gec=SMT,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2  |                     | 0,4 fit  |
| 30       | V26801-B100-V510,Bac=4230,Geh=SMT/2,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2  |                     | 6 fit    |
| 57       | V26801-B100-V535,Bac=4230,Geh=SMT/2,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2  |                     | 11,4 fit |
| 23       | V26803-B93-V2,Bac=4130,Tec=2000,Gec=SMT,Capacitor ceramic MDC,Tbmax=85,Umax=6.3,Zfr=100%,Tref=40,Ar=2,Vuv=.5,Ceramic Capacitor                  | SN 2    |                     | 46 fit   |

|    |  |        |     |     |
|----|--|--------|-----|-----|
| 5  | V26801-B100-V586, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 1   | fit |
| 2  | V26827-B561-V60, Bac=5211, Tec=2000, Conn./socket ins.<br>without el. load gold multiple cont. 60 pins, Vf=60, Zfr=100%, Tref=40<br>Ar=0.05, Stiftleiste             | SN 3   | 6   | fit |
| 2  | V26803-B103-V3, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Tbm=125, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Kondensator<br>Keramik COG                 | SN 2   | 4   | fit |
| 71 | V26803-B102-V1, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Zfr=100%, Tref=40, Ar=2, Vuv=.5, C x7r   | SN 2   | 142 | fit |
| 5  | V26803-B103-V4, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Tbm=125, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Kondensator<br>Keramik COG                 | SN 2   | 10  | fit |
| 11 | V26803-B102-V2, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Zfr=100%, Tref=40, Ar=2, Vuv=.5, C x7r   | SN 2   | 22  | fit |
| 5  | V26803-B51-V28, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Tbm=85, Umax=16, Zfr=100%, Tref=40, Ar=2, Vuv=.5<br>keramikkondensator                        | SN 2   | 10  | fit |
| 1  | V26803-B102-V22, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Zfr=100%, Tref=40, Ar=2, Vuv=.5, C x7r  | SN 2   | 2   | fit |
| 1  | V26811-B905-V50, Bac=1640, Tec=4002, Geh=QFP/48, IC Analog<br>switched regulator CMOS LSI, Kl=300/3Kt, Rte=40, Rtjce=1, Tjmax=125, Zfr=100%<br>Tref=55, Ar=20, L6758 | SN 20  | 20  | fit |
| 7  | V26801-B100-V528, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 1,4 | fit |
| 5  | V26801-B100-V560, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 1   | fit |
| 48 | V26801-B100-V601, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 9,6 | fit |
| 3  | V26801-B100-V545, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,6 | fit |
| 2  | V26801-B100-V504, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,4 | fit |
| 2  | V26810-B583-V11, Bac=4520, Gec=SMT, PTC thermistor, Zfr=100%<br>Tref=40, Ar=5, NTC   | SN 5   | 10  | fit |
| 3  | V26801-B100-V532, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,6 | fit |
| 1  | V26801-B100-V633, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,2 | fit |
| 1  | V26801-B100-V623, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,2 | fit |
| 2  | V26801-B100-V679, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,4 | fit |
| 3  | V26801-B100-V638, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,6 | fit |
| 11 | V26801-B100-V683, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 2,2 | fit |
| 4  | V26801-B100-V520, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,8 | fit |
| 1  | V26801-B100-V592, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,2 | fit |
| 1  | V26801-B100-V657, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2 | 0,2 | fit |
| 3  | V26803-B78-V11, Bac=4140, Tec=2000, Gec=DRAHT, Cap.<br>Al-electrolytic non-solid electrolyte, Tbm=105, Zfr=100%, Tref=40, Ar=5<br>Vuv=.8, ps=1, Elko                 | SN 5   | 15  | fit |
| 22 | V26803-B91-V4, Bac=4130, Tec=2000, Gec=SMT, Capacitor ceramic<br>MDC, Tbm=85, Umax=16, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Ceramic Capacitor                            | SN 2   | 44  | fit |
| 31 | V26803-B51-V22, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Zfr=100%, Tref=40, Ar=2, Vuv=.5, KERKO  | SN 2   | 62  | fit |
| 5  | V26803-B51-V16, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Chip Capacitor                                      | SN 2   | 10  | fit |
| 8  | V26803-B103-V33, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=25, Tbm=125, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Kondensator<br>Keramik COG                | SN 2   | 16  | fit |
| 8  | V26803-B51-V530, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Tbm=85, Umax=50, Zfr=100%, Tref=40, Ar=2, Vuv=.5<br>keramikkondensator                       | SN 2   | 16  | fit |
| 8  | V26803-B78-V7, Bac=4140, Tec=2000, Gec=DRAHT, Cap.<br>Al-electrolytic non-solid electrolyte, Tbm=105, Zfr=100%, Tref=40, Ar=5<br>Vuv=.8, ps=1, Elko                  | SN 5   | 40  | fit |

|    |   |        |     |     |
|----|---|--------|-----|-----|
| 1  | V26813-B1102-V40, Bac=4310, Tec=2000, Geh=SMD/2<br>Inductor/small transformer High frequency > 25 kHz, Zfr=100%, Tref=55, Ar=5<br>Spule   | SN 5   | 5   | fit |
| 4  | V26813-B1092-V40, Bac=4310, Tec=2000, Geh=SMD/2<br>Inductor/small transformer High frequency > 25 kHz, Zfr=100%, Tref=55, Ar=5<br>Spule   | SN 5   | 20  | fit |
| 5  | V26811-B906-V60, Bac=1420, Tec=4001, Geh=QFN/8, IC Standard<br>bus interface/analog switch CMOS MSI, Kl=10/100g, Tumax=85, Tjmax=125, Rte=45<br>Zfr=100%, Tref=50, Ar=6/8, Ubv=5, Dual MOSFET Drive | SN 6/8 | 35  | fit |
| 12 | V26801-B76-V1, Bac=4230, Gec=SMT, Resistor metal film<br>Tbmax=85, Zfr=100%, Tref=55, Ar=0.2  | SN 0.2 | 2,4 | fit |
| 4  | V26801-B100-V655, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,8 | fit |
| 4  | V26801-B100-V547, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,8 | fit |
| 5  | V26810-B1003-V40, Bac=2140, Tec=3002, Geh=PL/8, Transistor<br>power MOS, Rte=59, Tjmax=150, Umax=30, Zfr=100%, Tref=100, Ar=60, Vuv=.5, AOn7514   | SN 60  | 300 | fit |
| 5  | V26810-B1002-V40, Bac=2140, Tec=3002, Geh=PL/8, Transistor<br>power MOS, Rte=53, Tjmax=150, Umax=30, Zfr=100%, Tref=100, Ar=60, Vuv=.5, AOn6508   | SN 60  | 300 | fit |
| 5  | V26810-B1004-V40, Bac=2220, Geh=SOD523/2, Schottky diode<br>Rte=667, Nmax=150, Zfr=100%, Tref=55, Ar=1, SDML10u45 Shottky Diode   | SN 1   | 5   | fit |
| 2  | V26803-B51-V14, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Chip Capacitor   | SN 2   | 4   | fit |
| 3  | V26803-B103-V15, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Tbmax=125, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Kondensator<br>Keramik COG   | SN 2   | 6   | fit |
| 1  | V26803-B102-V23, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=16, Zfr=100%, Tref=40, Ar=2, Vuv=.5, C x7r   | SN 2   | 2   | fit |
| 2  | V26803-B103-V32, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=25, Tbmax=125, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Kondensator<br>Keramik COG   | SN 2   | 4   | fit |
| 3  | V26813-B1113-V1, Bac=4310, Tec=2000, Geh=DRAHT/2<br>Inductor/small transformer High frequency > 25 kHz, Zfr=100%, Tref=55, Ar=5<br>Spule  | SN 5   | 15  | fit |
| 2  | V26811-B893-V40, Bac=1640, Tec=4002, Geh=QFP/12, IC Analog<br>switched regulator CMOS MSI, Kl=30/300t, Rte=165, Tumax=85, Zfr=100%, Tref=55<br>Ar=10, RT8238  | SN 10  | 20  | fit |
| 4  | V26811-B894-V40, Bac=1631, Tec=4002, Geh=SOT23/6, IC Analog<br>power amplifier/regulator <=1Watt CMOS SSI, Kl=2/30t, Rte=250, Umax=15<br>Zfr=100%, Tref=70, Ar=10, RT9194                           | SN 10  | 40  | fit |
| 2  | V26801-B100-V736, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,4 | fit |
| 1  | V26801-B100-V533, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,2 | fit |
| 1  | V26801-B100-V676, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,2 | fit |
| 1  | V26801-B100-V578, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,2 | fit |
| 4  | V26801-B100-V677, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,8 | fit |
| 1  | V26801-B100-V673, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,2 | fit |
| 1  | V26801-B100-V562, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,2 | fit |
| 5  | V26801-B100-V602, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 1   | fit |
| 3  | V26801-B76-V200, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2  | SN 0.2 | 0,6 | fit |
| 2  | V26801-B76-V208, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2  | SN 0.2 | 0,4 | fit |
| 1  | V26801-B100-V594, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,2 | fit |
| 1  | V26801-B100-V800, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2 | 0,2 | fit |
| 7  | V26810-B912-V70, Bac=2140, Tec=3002, Geh=SONDER/8, Transistor<br>power MOS, Tjmax=150, Rtjce=3.5, Rte=50, Rte=75, Zfr=100%, Tref=100, Ar=60, Vuv=.5<br>Power MOSFET                                 | SN 60  | 420 | fit |
| 6  | V26810-B924-V50, Bac=2110, Tec=1102, Gec=SOT23, Transistor<br>small signal bipolar NPN, Umax=80, Tjmax=150, Rte=625, Zfr=100%, Tref=55, Ar=3<br>Vuv=.5, Transistor                                  | SN 3   | 18  | fit |

|    |   |           |      |      |
|----|---|-----------|------|------|
| 2  | V26810-B989-V40,Bac=2110,Tec=3002,Geh=PL/8,Transistor<br>small signal MOSFET,Rte=35,Umax=20,Ari=69,Zfr=100%,Tref=55,Ar=5,Vuv=.5<br>AON6910 DUal Mosfet                          | SN 69     | 138  | fit< |
| 1  | V26810-B880-V80,Bac=2140,Tec=3002,Gec=SONDER,Transistor<br>power MOS,Tjmax=150,Rtjce=2.5,Rte=41,Zfr=100%,Tref=100,Ar=60,Vuv=.5,Power<br>MOSFET                                  | SN 60     | 60   | fit  |
| 23 | V26801-B100-V567,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2    | 4,6  | fit  |
| 1  | V26801-B100-V610,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2    | 0,2  | fit  |
| 2  | V26827-B401-V331,Bac=5211,Tec=1000,Conn./socket ins.<br>without el. load gold single cont. 240 pins,Vf=240,Zfr=100%,Tref=40,Ar=0.5<br>Sockel DDR III                            | SN 120    | 240  | fit  |
| 2  | V26827-B401-V330,Bac=5211,Tec=1000,Conn./socket ins.<br>without el. load gold single cont. 240 pins,Vf=240,Zfr=100%,Tref=40,Ar=0.5<br>Sockel DDR III                            | SN 120    | 240  | fit  |
| 1  | V26811-B851-V50,Bac=1310,Tec=4002,Geh=SOT23/6,IC ASIC<br>CMOS LSI,K1=100/1Kg,Tumax=85,Ntyp=5,Zfr=100%,Rtr=310,Tj=41.5,Ar=20,Tref=55<br>A=.9,Ea1=.3,Ea2=.7,pt=0.58,Digital-Popti | SN 11.6   | 11,6 | fit  |
| 2  | V26811-B560-V40,Bac=1610,Tec=4002,Geh=SO/8,IC Analog<br>Op-amplifier/compar. CMOS SSI,K1=2/30t,Tumax=70,Umax=16,Zfr=100%,Tref=45<br>Ar=2,Vuv=.7,ps=1,TLC272                     | SN 2      | 4    | fit  |
| 1  | V26811-B851-V40,Bac=1310,Tec=4002,Geh=SOT23/6,IC ASIC<br>CMOS LSI,K1=100/1Kg,Tumax=85,Ntyp=5,Zfr=100%,Rtr=310,Tj=41.5,Ar=20,Tref=55<br>A=.9,Ea1=.3,Ea2=.7,pt=0.58,Digital-Popti | SN 11.6   | 11,6 | fit  |
| 1  | V26811-B896-V40,Bac=1310,Tec=4002,Geh=SOT23/6,IC ASIC<br>CMOS LSI,K1=100/1Kg,Tumax=85,Ntyp=5,Rte=340,Zfr=100%,Tj=41.7,Ar=20,Tref=55<br>A=.9,Ea1=.3,Ea2=.7,pt=0.59,Digital-Popti | SN 11.7   | 11,7 | fit  |
| 6  | V26801-B100-V507,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2    | 1,2  | fit  |
| 2  | V26827-B463-V2,Bac=5210,Conn./socket inserted without el.<br>load 2 pins,Vf=2,Zfr=100%,Tref=40,Ar=0.05/5,Modulstift 1R 2P   | SN 0.1/10 | 10,1 | fit  |
| 1  | V26803-B103-V13,Bac=4130,Tec=2000,Gec=SMT,Capacitor<br>ceramic MDC,Umax=50,Tbmax=125,Zfr=100%,Tref=40,Ar=2,Vuv=.5,Kondensator<br>Keramik COG                                    | SN 2      | 2    | fit  |
| 6  | V26801-B100-V527,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2    | 1,2  | fit  |
| 2  | V26801-B100-V625,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2    | 0,4  | fit  |
| 2  | V26801-B100-V587,Bac=4230,Gec=SMT,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2    | 0,4  | fit  |
| 4  | V26803-B78-V8,Bac=4140,Tec=2000,Gec=DRAHT,Cap.<br>Al-electrolytic non-solid electrolyte,Tbmax=105,Zfr=100%,Tref=40,Ar=5<br>Vuv=.8,ps=1,Elko                                     | SN 5      | 20   | fit  |
| 2  | V26813-B356-V159,Bac=4320,Tec=1000,Geh=SMT/2,Inductor for<br>EMC applications <=3A,Tbmax=125,Zfr=100%,Tref=60,Ar=1.5,Spule  | SN 1.5    | 3    | fit  |
| 1  | V26811-B784-V40,Bac=1632,Tec=4001,Geh=SO/8,IC Analog<br>power amplifier/regulator >1Watt CMOS MSI,K1=30/300t,Tumax=85,Zfr=100%<br>Tref=90,Ar=50,LDO-Regler                      | SN 50     | 50   | fit  |
| 4  | V26801-B100-V599,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2    | 0,8  | fit  |
| 1  | V26801-B100-V613,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2    | 0,2  | fit  |
| 5  | V26810-B944-V40,Bac=2110,Tec=3000,Geh=SOT323/3,Transistor<br>small signal MOSFET,Umax=20,Zfr=100%,Tref=55,Ar=5,Vuv=.5,BSS214  | SN 5      | 25   | fit  |
| 5  | V26810-B926-V40,Bac=2110,Tec=3000,Geh=SOT323/3,Transistor<br>small signal MOSFET,Rte=625,Umax=60,Zfr=100%,Tref=55,Ar=5,Vuv=.5,2N7002  | SN 5      | 25   | fit  |
| 2  | V26811-B868-V40,Bac=1631,Tec=4002,Geh=SOT23/5,IC Analog<br>power amplifier/regulator <=1Watt CMOS SSI,K1=2/30t,Rte=250,Tumax=85<br>Umax=6,Zfr=100%,Tref=70,Ar=10,RT9193         | SN 10     | 20   | fit  |
| 4  | V26801-B100-V614,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2    | 0,8  | fit  |
| 3  | V26803-B103-V16,Bac=4130,Tec=2000,Gec=SMT,Capacitor<br>ceramic MDC,Umax=50,Tbmax=125,Zfr=100%,Tref=40,Ar=2,Vuv=.5,Kondensator<br>Keramik COG                                    | SN 2      | 6    | fit  |
| 1  | V26813-B356-V150,Bac=4320,Tec=1000,Geh=SMT/2,Inductor for<br>EMC applications <=3A,Tbmax=125,Zfr=100%,Tref=60,Ar=1.5,Spule  | SN 1.5    | 1,5  | fit  |
| 1  | V26813-B1069-V40,Bac=4310,Tec=2000,Geh=SMD/2<br>Inductor/small transformer High frequency > 25 kHz,Zfr=100%,Tref=55,Ar=5<br>Spule   | SN 5      | 5    | fit  |
| 1  | V26811-B862-V40,Bac=1640,Tec=4002,Geh=QFN/10,IC Analog<br>switched regulator CMOS LSI,K1=300/3Kt,Tjmax=150,Rtjce=8.2,Rte=70,Zfr=100%<br>Tref=55,Ar=20,PWMController             | SN 20     | 20   | fit  |

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| 6  | V26801-B100-V620, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2  | 1,2 fit  |
| 1  | V26801-B100-V748, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2  | 0,2 fit  |
| 5  | V26810-B925-V50, Bac=2130, Tec=1200, Geh=SOT323/3, Transistor<br>low power bip PNP, Rte=625, Umax=80, Zfr=100%, Tref=85, Ar=20, Vuv=.5, BC856   | SN 20   | 100 fit  |
| 2  | V26802-B16-V15, Bac=4251, Geh=SMT/8, Resistor network<br>standard, Vf=4, Zfr=100%, Tref=55, Ar=0.1, Widerstandsnetzwerk   | SN 0.4  | 0,8 fit  |
| 3  | V26803-B102-V10, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Zfr=100%, Tref=40, Ar=2, Vuv=.5, C x7r   | SN 2    | 6 fit    |
| 2  | V26811-B870-V40, Bac=1312, Tec=4002, Geh=SO/5, IC ASIC analog<br>CMOS SSI, Tumax=85, Kl=10g, Rte=250, Zfr=100%, Tref=55, Ar=20, reset   | SN 20   | 40 fit   |
| 1  | V26808-B2550-V50, Bac=1410, Tec=4502, Geh=SSOP/14, IC<br>Standard logic AC MOS MSI, Kl=10/100g, Rte=113, Tumax=85, Zfr=100%, Tref=45, Ar=3<br>74AHC132  | SN 3    | 3 fit    |
| 2  | V26801-B100-V529, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2  | 0,4 fit  |
| 10 | V26810-B920-V40, Bac=2220, Geh=SOT323/3, Schottky diode<br>Rte=625, Zfr=100%, Tref=55, Ar=1, BAT54  | SN 1    | 10 fit   |
| 1  | V26802-B16-V20, Bac=4251, Geh=SMT/8, Resistor network<br>standard, Vf=4, Zfr=100%, Tref=55, Ar=0.1, Widerstandsnetzwerk   | SN 0.4  | 0,4 fit  |
| 1  | V26803-B102-V25, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=6.3, Zfr=100%, Tref=40, Ar=2, Vuv=.5, C x7r  | SN 2    | 2 fit    |
| 1  | LM393D, V26811-B129-V41, Bac=1610, Tec=1002, Geh=SO/8, IC<br>Analog Op-amplifier/compar. Bipolar SSI, Kl=1/30t, Rttq=140/100/*, Umax=36<br>Zfr=100%, Tref=55, Ar=3, Vuv=.7, ps=1, 2X KOMPARATOR LM393D-VALVO LM393M-RAYTH   | SN 3    | 3 fit    |
| 1  | V26801-B76-V605, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2  | SN 0.2  | 0,2 fit  |
| 4  | V26810-B612-V70, Bac=2110, Tec=1102, Gec=SOT363, Transistor<br>small signal bipolar NPN, Umax=50, Vf=2, Tjmax=150, Zfr=100%, Tref=55, Ar=3<br>Vuv=.5, Transistor  | SN 6    | 24 fit   |
| 4  | V26810-B754-V50, Bac=2120, Tec=1002, Geh=SO/6, Transistor<br>array bipolar, Vf=2, Zfr=100%, Tref=55, Ar=12, Vuv=.5, Dual Transistor   | SN 12   | 48 fit   |
| 1  | V26810-B921-V40, Bac=2220, Geh=SOT323/3, Schottky diode<br>Vf=2, Rte=625, Zfr=100%, Tref=55, Ar=1, BAW54  | SN 2    | 2 fit    |
| 2  | V26810-B856-V40, Bac=2210, Tec=0002, Geh=SOD323/3, Universal<br>diode, Rte=625, Zfr=100%, Tref=55, Ar=1, Diode  | SN 1    | 2 fit    |
| 1  | V26802-B16-V19, Bac=4251, Geh=SMT/8, Resistor network<br>standard, Vf=4, Zfr=100%, Tref=55, Ar=0.1, Widerstandsnetzwerk   | SN 0.4  | 0,4 fit  |
| 1  | 74LVC74AD, V26808-B2762-V50, Bac=1410, Tec=4502, Geh=SO/14, IC<br>Standard logic AC MOS SSI, Kl=1/10g, Rte=188, Tumax=85, Ntyp=10, Zfr=100%<br>Tj=41.9, Ar=3, Tref=45, A=.9, Ea1=.3, Ea2=.7, pt=0.88, 2X Positive-Edge-Triggered<br>D-Type FLIP-FLOP SN74LVC74APWLE-TEXAS | SN 2.65 | 2,6 fit  |
| 1  | 74LVC14D, V26808-B2778-V50, Bac=1410, Tec=4502, Geh=SO/14, IC<br>Standard logic AC MOS SSI, Kl=1/10g, Rte=188, Tumax=85, Ntyp=10, Zfr=100%<br>Tj=41.9, Ar=3, Tref=45, A=.9, Ea1=.3, Ea2=.7, pt=0.88, 6X SCHMITT-TRIGGER INVERTER<br>SN74LVC14APWLE-TEXAS                  | SN 2.65 | 2,6 fit  |
| 1  | V26808-B8594-V30, Bac=1260, Tec=4002, Geh=PGAP/942, IC µP<br>Peripheral CMOS, Kl=10M/100Mg, Tumax=70, Are=270, Zfr=100%, Tref=90<br>Pantherpoint  | SN 270  | 270 fit« |
| 4  | V26803-B103-V36, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=50, Tbm=125, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Kondensator<br>Keramik COG   | SN 2    | 8 fit    |
| 2  | V26823-B24-V7, Bac=4610, Geh=SMT/2, Crystal, Fnen=25<br>Zfr=100%, Tref=40, Ar=15, Quarz   | SN 15   | 30 fit   |
| 3  | V26801-B100-V588, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2  | 0,6 fit  |
| 1  | V26803-B51-V26, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Tbm=85, Umax=25, Zfr=100%, Tref=40, Ar=2, Vuv=.5<br>keramikkondensator   | SN 2    | 2 fit    |
| 6  | V26803-B51-V21, Bac=4130, Tec=2000, Gec=SMT, Capacitor<br>ceramic MDC, Umax=25, Zfr=100%, Tref=40, Ar=2, Vuv=.5, KERKO X7R  | SN 2    | 12 fit   |
| 1  | V26808-B2804-V41, Bac=1410, Tec=4500, Geh=SOP/8, IC Standard<br>logic AC MOS SSI, Kl=2g, Tumax=85, Zfr=100%, Tref=45, Ar=3, 741vc08   | SN 3    | 3 fit    |
| 1  | V26801-B100-V674, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2  | 0,2 fit  |
| 2  | V26801-B100-V626, Bac=4230, Gec=SMT, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2  | 0,4 fit  |
| 1  | V26801-B100-V658, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2  | 0,2 fit  |
| 1  | V26801-B100-V681, Bac=4230, Geh=SMT/2, Resistor metal film<br>Zfr=100%, Tref=55, Ar=0.2, CHIP R   | SN 0.2  | 0,2 fit  |

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| 5  | V26801-B100-V513,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2   | 1   | fit |
| 1  | V26801-B100-V597,Bac=4230,Gec=SMT,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2   | 0,2 | fit |
| 7  | V26801-B100-V514,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2   | 1,4 | fit |
| 10 | V26801-B100-V579,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2   | 2   | fit |
| 7  | V26802-B16-V12,Bac=4251,Geh=SMT/8,Resistor network<br>standard,Vf=4,Zfr=100%,Tref=55,Ar=0.1,Widerstandsnetzwerk  | SN 0.4   | 2,8 | fit |
| 7  | V26802-B16-V16,Bac=4251,Geh=SMT/8,Resistor network<br>standard,Vf=4,Zfr=100%,Tref=55,Ar=0.1,Widerstandsnetzwerk  | SN 0.4   | 2,8 | fit |
| 1  | V26823-B7023-V1,Bac=4610,Geh=SMT/4,Crystal,Fnen=0.032<br>Zfr=100%,Tref=40,Ar=15,Quarz  | SN 15    | 15  | fit |
| 1  | V26801-B100-V737,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2   | 0,2 | fit |
| 1  | V26898-B540-V300,Bac=5240,Tec=1000,IC-socket tin single<br>contacts 2 pins,Vf=2,Zfr=100%,Tref=40,Ar=1.5,Batterie - Halter 2-polig<br>DM-001-BECU-DATA MODUL GMBH                                 | SN 3     | 3   | fit |
| 1  | V26898-B540-V3,Bac=6510,Tec=3000,Primary cell/battery<br>Lithium,Tbmax=85,Zfr=100%,Ar=20,Tref=40,Mangandioxyd-Lithium-Knopfzelle   | SN 20    | 20  | fit |
| 23 | V26801-B100-V537,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2   | 4,6 | fit |
| 2  | V26813-B356-V77,Bac=4320,Geh=SMT/2,Inductor for EMC<br>applications,Zfr=100%,Tref=60,Ar=1.5/3,Choke  | SN 1.5/3 | 4,5 | fit |
| 2  | V26811-B895-V40,Bac=1631,Tec=4002,Geh=TSOP/5,IC Analog<br>power amplifier/regulator <=1Watt CMOS SSI,K1=2/30t,Rte=333,Tumax=85<br>Zfr=100%,Tref=70,Ar=10,DS9030                                  | SN 10    | 20  | fit |
| 2  | V26801-B100-V621,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2   | 0,4 | fit |
| 9  | V26802-B16-V17,Bac=4251,Geh=SMT/8,Resistor network<br>standard,Vf=4,Zfr=100%,Tref=55,Ar=0.1,Widerstandsnetzwerk  | SN 0.4   | 3,6 | fit |
| 1  | V26808-B8625-V40,Bac=1170,Tec=4002,Geh=SO/8,IC Memory<br>FLASH EPROM CMOS 64M,K1=64Mb,Tumax=85,Zfr=100%,Tref=55,Ar=70,64MB Flash   | SN 70    | 70  | fit |
| 1  | V26827-B464-V10,Bac=5240,Tec=1000,IC-socket tin single<br>contacts 10 pins,Vf=10,Zfr=100%,Tref=40,Ar=1.5,Steckverbinder  | SN 15    | 15  | fit |
| 4  | V26802-B16-V11,Bac=4251,Geh=SMT/8,Resistor network<br>standard,Vf=4,Zfr=100%,Tref=55,Ar=0.1,Widerstandsnetzwerk  | SN 0.4   | 1,6 | fit |
| 5  | V26802-B16-V2,Bac=4251,Geh=SMT/8,Resistor network<br>standard,Vf=4,Zfr=100%,Tref=55,Ar=0.1,Widerstandsnetzwerk   | SN 0.4   | 2   | fit |
| 7  | V26803-B78-V9,Bac=4140,Tec=2000,Gec=DRAHT,Cap.<br>Al-electrolytic non-solid electrolyte,Tbmax=105,Zfr=100%,Tref=40,Ar=5<br>Vuv=.8,ps=1,Elko  | SN 5     | 35  | fit |
| 1  | V26801-B76-V3,Bac=4230,Gec=SMT,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,Chip Resistor  | SN 0.2   | 0,2 | fit |
| 1  | V26808-B8467-V30,Bac=1260,Tec=4002,Geh=QFP/128,IC µP<br>Peripheral CMOS SLSI,K1=100Kg/1Mg,Tumax=70,Zfr=100%,Tref=90,Ar=80,Super I/O  | SN 80    | 80  | fit |
| 1  | V26811-B858-V40,Bac=1410,Tec=4002,Geh=SO/3,IC Standard<br>logic CMOS SSI,K1=1/10g,Tumax=85,Rte=250,Zfr=100%,Tref=45,Ar=3,Ubv=5,Reset<br>IC   | SN 3     | 3   | fit |
| 1  | V26801-B100-V524,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2   | 0,2 | fit |
| 1  | V26801-B100-V670,Bac=4230,Geh=SMT/2,Resistor metal film<br>Zfr=100%,Tref=55,Ar=0.2,CHIP R  | SN 0.2   | 0,2 | fit |
| 1  | V26802-B16-V6,Bac=4251,Geh=SMT/8,Resistor network<br>standard,Vf=8,Zfr=100%,Tref=55,Ar=0.1,R-Array   | SN 0.8   | 0,8 | fit |
| 1  | V26827-B463-V3,Bac=5211,Tec=2000,Conn./socket ins.<br>without el. load gold multiple cont. 3 pins,Vf=3,Tbmax=70,Zfr=100%,Tref=40<br>Ar=0.05,Stift  | SN 0.15  | 0,2 | fit |
| 15 | V26803-B103-V35,Bac=4130,Tec=2000,Gec=SMT,Capacitor<br>ceramic MDC,Umax=50,Tbmax=125,Zfr=100%,Tref=40,Ar=2,Vuv=.5,Kondensator<br>Keramik COG   | SN 2     | 30  | fit |
| 1  | V26808-B7659-V50,Bac=1420,Tec=4002,Geh=SO/20,IC Standard<br>bus interface/analog switch CMOS MSI,K1=10/100g,Tumax=70,Zfr=100%,Tref=50<br>Ar=6/8,Ubv=5,Interface                                  | SN 6/8   | 7   | fit |
| 5  | V26810-B919-V40,Bac=2220,Geh=SOT323/3,Schottky diode<br>Vf=2,Rte=625,Zfr=100%,Tref=55,Ar=1,BAV70   | SN 2     | 10  | fit |
| 1  | V26827-B431-V3,Bac=5211,Tec=2000,Pin=26,Conn./socket ins.<br>without el. load gold multiple cont. 26 pins,Vf=26,Geh=L40.3B8.8H9.5<br>Zfr=100%,Tref=40,Ar=0.05,STIFTLLEISTE 26-POLIG 2526-6002-3M | SN 1.3   | 1,3 | fit |

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| 1  | V26802-B16-V7,Bac=4251,Geh=SMT/8,Resistor network standard,Vf=8,Zfr=100%,Tref=55,Ar=0.1,R-Array  | SN 0.8   | 0,8 fit  |
| 2  | V26810-B397-V65,Bac=4530,Gec=SMT,NTC thermistor,Zfr=100% Tref=40,Ar=3,PTC  | SN 3     | 6 fit    |
| 1  | V26801-B71-V200,Bac=4230,Gec=SMT,Resistor metal film Tbxmax=85,Zfr=100%,Tref=55,Ar=0.2,Chip Resistor   | SN 0.2   | 0,2 fit  |
| 5  | V26810-B962-V40,Bac=2210,Geh=SMT/8,Universal diode,Vf=4 Zfr=100%,Tref=55,Ar=1,ESD-Diode  | SN 4     | 20 fit   |
| 1  | V26827-B389-V205,Bac=5211,Tec=2000,Conn./socket ins. without el. load gold multiple cont. 12 pins,Vf=12,Zfr=100%,Tref=40 Ar=0.05,Steckverbinder          | SN 0.6   | 0,6 fit  |
| 1  | V26827-B392-V443,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 14 pins,Vf=14,Zfr=100%,Tref=40,Ar=0.5 SATA 3 dual                | SN 7     | 7 fit    |
| 2  | V26827-B392-V430,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 14 pins,Vf=14,Zfr=100%,Tref=40,Ar=0.5 Serial ATA kombi           | SN 7     | 14 fit   |
| 8  | V26813-B356-V163,Bac=4420,Gec=SMT,RCL-filter,Tbxmax=85 Zfr=100%,Tref=40,Ar=10,Filter   | SN 10    | 80 fit   |
| 12 | V26802-B17-V2,Bac=4251,Geh=SMT/4,Resistor network standard,Vf=2,Zfr=100%,Tref=55,Ar=0.1,RAC  | SN 0.2   | 2,4 fit  |
| 5  | V26813-B356-V78,Bac=4320,Geh=SMT/2,Inductor for EMC applications,Zfr=100%,Tref=60,Ar=1.5/3,Choke   | SN 1.5/3 | 11,2 fit |
| 5  | V26810-B397-V61,Bac=4530,Gec=SMT,NTC thermistor,Zfr=100% Tref=40,Ar=3,PTC  | SN 3     | 15 fit   |
| 1  | V26827-B478-V32,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 18 pins,Vf=18,Zfr=100%,Tref=40,Ar=0.5 USB stehend 2 fach          | SN 9     | 9 fit    |
| 1  | V26827-B478-V44,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 16 pins,Vf=16,Zfr=100%,Tref=40,Ar=0.5 Serienbussteckverbinder     | SN 8     | 8 fit    |
| 6  | V26802-B17-V1,Bac=4251,Geh=SMT/4,Resistor network standard,Vf=2,Zfr=100%,Tref=55,Ar=0.1,RAC  | SN 0.2   | 1,2 fit  |
| 1  | V26827-B567-V19,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 19 pins,Vf=19,Zfr=100%,Tref=40,Ar=0.5 Stecker 2R219P              | SN 9.5   | 9,5 fit  |
| 2  | V26827-B470-V111,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 9 pins,Vf=9,Zfr=100%,Tref=40,Ar=0.5 Stiftleiste                  | SN 4.5   | 9 fit    |
| 2  | V26827-B454-V139,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 164 pins,Vf=164,Zfr=100%,Tref=40,Ar=0.5 PCI express Leiste       | SN 82    | 164 fit  |
| 32 | V26803-B102-V21,Bac=4130,Tec=2000,Gec=SMT,Capacitor ceramic MDC,Umax=50,Zfr=100%,Tref=40,Ar=2,Vuv=.5,C x7r   | SN 2     | 64 fit   |
| 1  | V26827-B454-V36,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 36 pins,Vf=36,Tbxmax=70,Zfr=100%,Tref=40 Ar=0.5,PCI Leiste        | SN 18    | 18 fit   |
| 2  | V26801-B100-V647,Bac=4230,Geh=SMT/2,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2   | 0,4 fit  |
| 1  | V26827-B454-V620,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 120 pins,Vf=120,Zfr=100%,Tref=40,Ar=0.5 PCI Leiste               | SN 60    | 60 fit   |
| 1  | V26801-B100-V573,Bac=4230,Geh=SMT/2,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2   | 0,2 fit  |
| 1  | V26801-B100-V515,Bac=4230,Geh=SMT/2,Resistor metal film Zfr=100%,Tref=55,Ar=0.2,CHIP R   | SN 0.2   | 0,2 fit  |
| 1  | V26827-B464-V24,Bac=5211,Tec=1000,Conn./socket ins. without el. load gold single cont. 23 pins,Vf=23,Zfr=100%,Tref=40,Ar=0.5 Stiftleiste                 | SN 11.5  | 11,5 fit |
| 3  | V26810-B757-V1,Bac=3211,Tec=0002,LED radial/SMT,Tumax=70 Imax=0.01,Zfr=100%,Tref=45,Ar=1.5/4,Viv=.5,LED  | SN 1.5/4 | 8,2 fit  |
| 3  | V26802-B16-V10,Bac=4251,Geh=SMT/8,Resistor network standard,Vf=4,Zfr=100%,Tref=55,Ar=0.1,Widerstandsnetzwerk   | SN 0.4   | 1,2 fit  |
| 1  | V26827-B351-V105,Bac=5213,Tec=1000,Conn./socket ins. without el. load tin single cont. 4 pins,Vf=4,Tbxmax=85,Zfr=100%,Tref=40 Ar=0.75,Stiftleiste 4polig | SN 3     | 3 fit    |
| 2  | V26827-B351-V104,Bac=5213,Tec=1000,Conn./socket ins. without el. load tin single cont. 4 pins,Vf=4,Tbxmax=85,Zfr=100%,Tref=40 Ar=0.75,Stiftleiste 4polig | SN 3     | 6 fit    |
| 1  | V26827-B351-V9,Bac=5213,Tec=2000,Conn./socket ins. without el. load tin multiple cont. 4 pins,Vf=4,Zfr=100%,Tref=40,Ar=0.08                              | SN 0.3   | 0,3 fit  |

|    |   |          |      |      |
|----|---|----------|------|------|
| 6  | V26803-B103-V9, Bac=4130, Tec=2000, Gec=SMT, Capacitor ceramic MDC, Umax=50, Tmax=125, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Kondensator Keramik COG                               | SN 2     | 12   | fit  |
| 3  | V26813-B356-V94, Bac=4320, Geh=SMT/2, Inductor for EMC applications, Imax=3, Tmax=125, Zfr=100%, Tref=60, Ar=1.5/3, Choke   | SN 1.5/3 | 6,8  | fit  |
| 8  | V26801-B100-V556, Bac=4230, Geh=SMT/2, Resistor metal film Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2   | 1,6  | fit  |
| 1  | V26827-B163-V263, Bac=5211, Tec=1000, Conn./socket ins. without el. load gold single cont. 33 pins, Vf=33, Zfr=100%, Tref=40, Ar=0.5  | SN 16.5  | 16,5 | fit  |
| 1  | V26808-B2671-V50, Bac=1420, Tec=5002, Geh=SO/14, IC Standard bus interface BICMOS SSI, K1=4g, Tmax=85, Rte=113, Zfr=100%, Tref=95, Ar=38/51 CBT3126                           | SN 38/51 | 44,5 | fit  |
| 1  | V26827-B163-V20, Bac=5211, Tec=1000, Conn./socket ins. without el. load gold single cont. 20 pins, Vf=20, Zfr=100%, Tref=40, Ar=0.5   | SN 10    | 10   | fit  |
| 10 | V26803-B90-V5, Bac=4130, Tec=2000, Gec=SMT, Capacitor ceramic MDC, Tmax=85, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Ceramic Capacitor  | SN 2     | 20   | fit  |
| 1  | V26808-B8483-V30, Bac=1260, Tec=4002, Geh=QFN/48, IC $\mu$ P Peripheral CMOS MSI, K1=1K/100kt, Tmax=70, Zfr=100%, Tref=80, Ar=50 AudioController                              | SN 50    | 50   | fit  |
| 2  | V26801-B100-V628, Bac=4230, Gec=SMT, Resistor metal film Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2   | 0,4  | fit  |
| 1  | V26802-B14-V18, Bac=4251, Geh=SMT/8, Resistor network standard, Vf=4, Zfr=100%, Tref=55, Ar=0.1, Widerstandsnetzwerk  | SN 0.4   | 0,4  | fit  |
| 3  | V26802-B16-V13, Bac=4251, Geh=SMT/8, Resistor network standard, Vf=4, Zfr=100%, Tref=55, Ar=0.1, Widerstandsnetzwerk  | SN 0.4   | 1,2  | fit  |
| 1  | V26827-B470-V910, Bac=5211, Tec=1000, Conn./socket ins. without el. load gold single cont. 9 pins, Vf=9, Zfr=100%, Tref=40, Ar=0.5 Stifteleiste                               | SN 4.5   | 4,5  | fit  |
| 1  | V26827-B441-V365, Bac=5211, Tec=1000, Conn./socket ins. without el. load gold single cont. 13 pins, Vf=13, Zfr=100%, Tref=40, Ar=0.5 Audiobuchsen                             | SN 6.5   | 6,5  | fit  |
| 1  | V26808-B8473-V30, Bac=1260, Tec=4002, Geh=LGA/48, IC $\mu$ P Peripheral CMOS SLSI, K1=100K/1000Kg, Tmax=70, Ari=70, Zfr=100%, Tref=90, Ar=80 Lewisville LAN                   | SN 70    | 70   | fit« |
| 1  | V26813-B356-V147, Bac=4310, Tec=2000, Geh=SMT/2 Inductor/small transformer High frequency > 25 kHz, Tmax=85, Zfr=100% Tref=55, Ar=5, Spule                                    | SN 5     | 5    | fit  |
| 1  | V26827-B391-V228, Bac=5211, Tec=1000, Conn./socket ins. without el. load gold single cont. 22 pins, Vf=22, Zfr=100%, Tref=40, Ar=0.5 lan+2USB Stecker                         | SN 11    | 11   | fit  |
| 1  | V26808-B7888-V75, Bac=1210, Tec=4002, Geh=SO/28, IC $\mu$ P $\mu$ C SigP Processor Controller CMOS, K1=100K/1Mg, Tmax=70, Zfr=100%, Tref=90 Ar=80, Controller                 | SN 80    | 80   | fit  |
| 1  | V26827-B469-V902, Bac=5211, Tec=1000, Conn./socket ins. without el. load gold single cont. 2 pins, Vf=2, Zfr=100%, Tref=40, Ar=0.5 Stifteleiste 2 pol. mit Jumper             | SN 1     | 1    | fit  |
| 1  | V26802-B16-V14, Bac=4251, Geh=SMT/8, Resistor network standard, Vf=4, Zfr=100%, Tref=55, Ar=0.1, Widerstandsnetzwerk  | SN 0.4   | 0,4  | fit  |
| 1  | V26803-B7078-V2, Bac=4140, Tec=1000, Geh=SMD/2, Cap. Al-electrolytic solid electrolyte, Zfr=100%, Tref=40, Ar=3, Vuv=.8, ps=1, Elko   | SN 3     | 3    | fit  |
| 1  | V26827-B406-V241, Bac=5213, Tec=1000, Conn./socket ins. without el. load tin single cont. 24 pins, Vf=24, Zfr=100%, Tref=40, Ar=0.75 Stifteleiste                             | SN 18    | 18   | fit  |
| 1  | V26827-B406-V304, Bac=5213, Tec=1000, Conn./socket ins. without el. load tin single cont. 4 pins, Vf=4, Zfr=100%, Tref=40, Ar=0.75 Stecker                                    | SN 3     | 3    | fit  |
| 1  | V26803-B102-V6, Bac=4130, Tec=2000, Gec=SMT, Capacitor ceramic MDC, Umax=50, Zfr=100%, Tref=40, Ar=2, Vuv=.5, C x7r   | SN 2     | 2    | fit  |
| 1  | V26827-B564-V1, Bac=5211, Tec=1000, Conn./socket ins. without el. load gold single cont. 1 pins, Vf=1, Zfr=100%, Tref=40, Ar=0.5 Kontakt                                      | SN 0.5   | 0,5  | fit  |
| 1  | V26803-B93-V5, Bac=4130, Tec=2000, Gec=SMT, Capacitor ceramic MDC, Tmax=85, Umax=50, Zfr=100%, Tref=40, Ar=2, Vuv=.5, Ceramic Capacitor                                       | SN 2     | 2    | fit  |
| 1  | V26811-B649-V55, Bac=1632, Tec=4002, Geh=SO/4, IC Analog power amplifier/regulator >1Watt CMOS MSI, K1=30/300t, Tjmax=150, Rte=60 Zfr=100%, Tref=90, Ar=50, Voltage Regulator | SN 50    | 50   | fit  |
| 1  | V26801-B100-V672, Bac=4230, Geh=SMT/2, Resistor metal film Zfr=100%, Tref=55, Ar=0.2, CHIP R  | SN 0.2   | 0,2  | fit  |
| 1  | V26810-B966-V40, Bac=2140, Tec=3002, Geh=TSOP/6, Transistor power MOS, Rte=80, Tjmax=150, Umax=30, Zfr=100%, Tref=100, Ar=60, Vuv=.5, AO6401A                                 | SN 60    | 60   | fit  |
| 4  | V26810-B759-V1, Bac=3211, Tec=0002, LED radial/SMT, Tmax=70 Zfr=100%, Tref=45, Ar=1.5/4, Viv=.5, LED  | SN 1.5/4 | 11   | fit  |



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| 1 | V26827-B351-V16,Bac=5213,Tec=1000,Conn./socket ins.<br>without el. load tin single cont. 4 pins,Vf=4,Tbmax=70,Zfr=100%,Tref=40<br>Ar=0.75,Stiftleiste | SN 3    | 3 fit     |
| 1 | V26827-B470-V296,Bac=5211,Tec=1000,Conn./socket ins.<br>without el. load gold single cont. 9 pins,Vf=9,Zfr=100%,Tref=40,Ar=0.5<br>Stiftleiste         | SN 4.5  | 4,5 fit   |
| 7 | 502 Bac=5112,Soldering point machine,Ar=0.03,Tref=40  | SN 0.03 | 225,1 fit |